Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

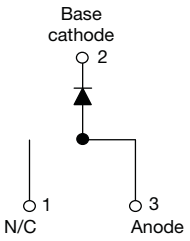
Vishay Semiconductor/Diodes Division
VS-MBRB1035PBF

For any questions, you can email us directly:
sales@integrated-circuit.com

VS-MBRB1035PbF, VS-MBRB1045PbF

High Performance Schottky Rectifier, 10 A

TO-263AB (D^2PAK)



FEATURES

- 150 °C T_J operation
- TO-220 and D^2PAK packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY	
Package	TO-263AB (D^2PAK)
$I_{F(AV)}$	10 A
V_R	35 V, 45 V
V_F at I_F	0.57 V
I_{RM} max.	15 mA at 125 °C
T_J max.	150 °C
Diode variation	Single die
E_{AS}	8.0 mJ

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	10	A
I_{FRM}	T_C = 135 °C	20	
V_{RRM}		35, 45	V
I_{FSM}	t_p = 5 µs sine	1060	A
V_F	10 A_{pk}, T_J = 125 °C	0.57	V
T_J	Range	-65 to +150	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRB1035PbF	VS-MBRB1045PbF	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	T_C = 135 °C, rated V_R		10	A
Peak repetitive forward current	I_{FRM}	Rated V_R, square wave, 20 kHz, T_C = 135 °C		20	
Non-repetitive surge current	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1060	
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 2 A, L = 4 mH		8	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		2	A

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM} (1)	20 A	T_J = 25 °C	0.84	V
		10 A	T_J = 125 °C	0.57	
		20 A		0.72	
Maximum instantaneous reverse current	I_{RM} (1)	T_J = 25 °C	Rated DC voltage	0.1	mA
		T_J = 125 °C		15	
Threshold voltage	$V_{F(TO)}$	T_J = T_J maximum		0.354	V
Forward slope resistance	r_t			17.6	mΩ
Maximum junction capacitance	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		600	pF
Typical series inductance	L_S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range		T_J		-65 to +150	°C
Maximum storage temperature range		T_{Stg}		-65 to +175	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	2.0	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style D^2PAK	MBRB1035	
				MBRB1045	

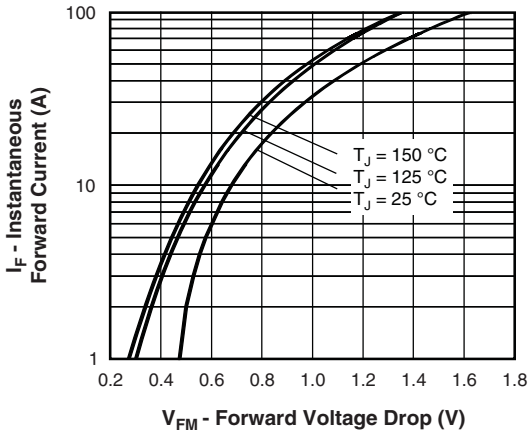


Fig. 1 - Maximum Forward Voltage Drop Characteristics

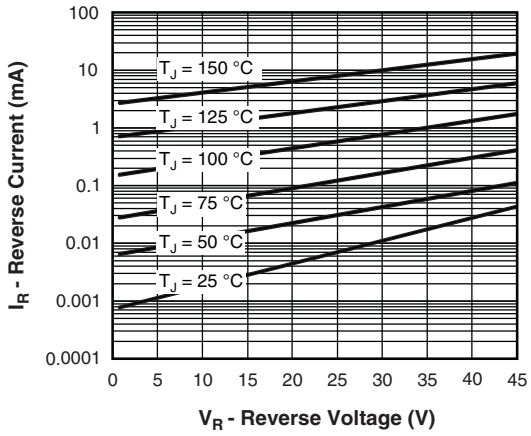


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

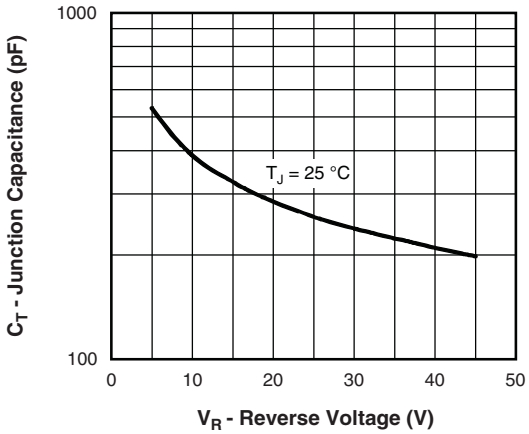


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

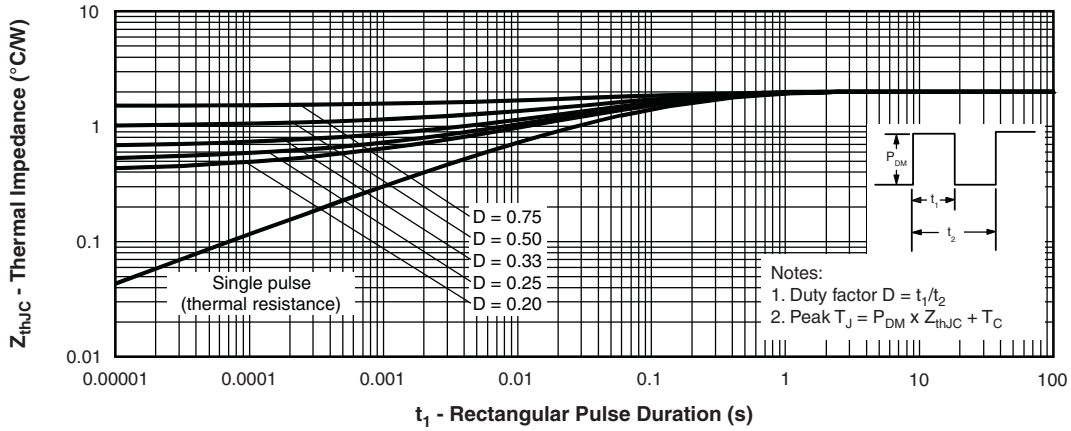


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

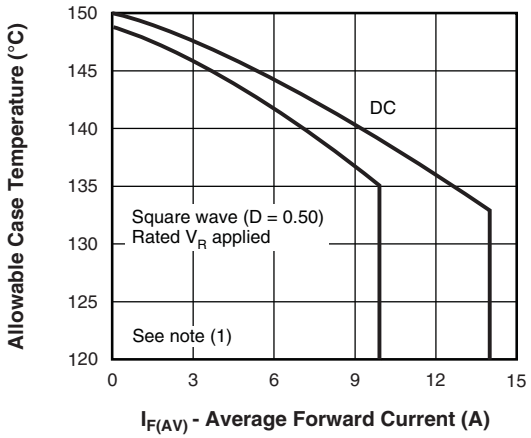


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

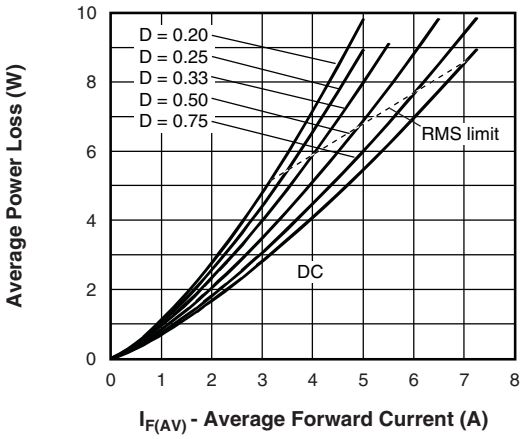


Fig. 6 - Forward Power Loss Characteristics

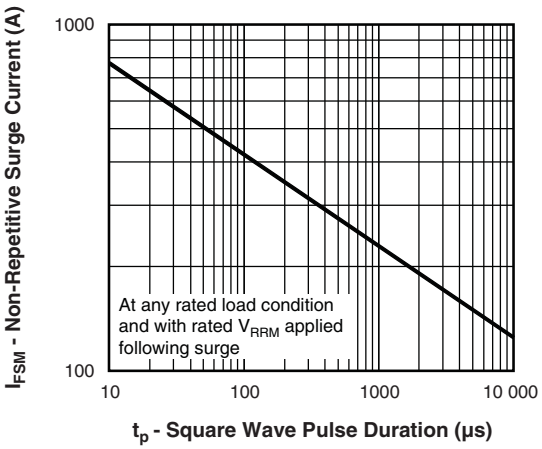


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

ORDERING INFORMATION TABLE

Device code

VS-	MBR	B	10	45	TRL	PbF
1	2	3	4	5	6	7

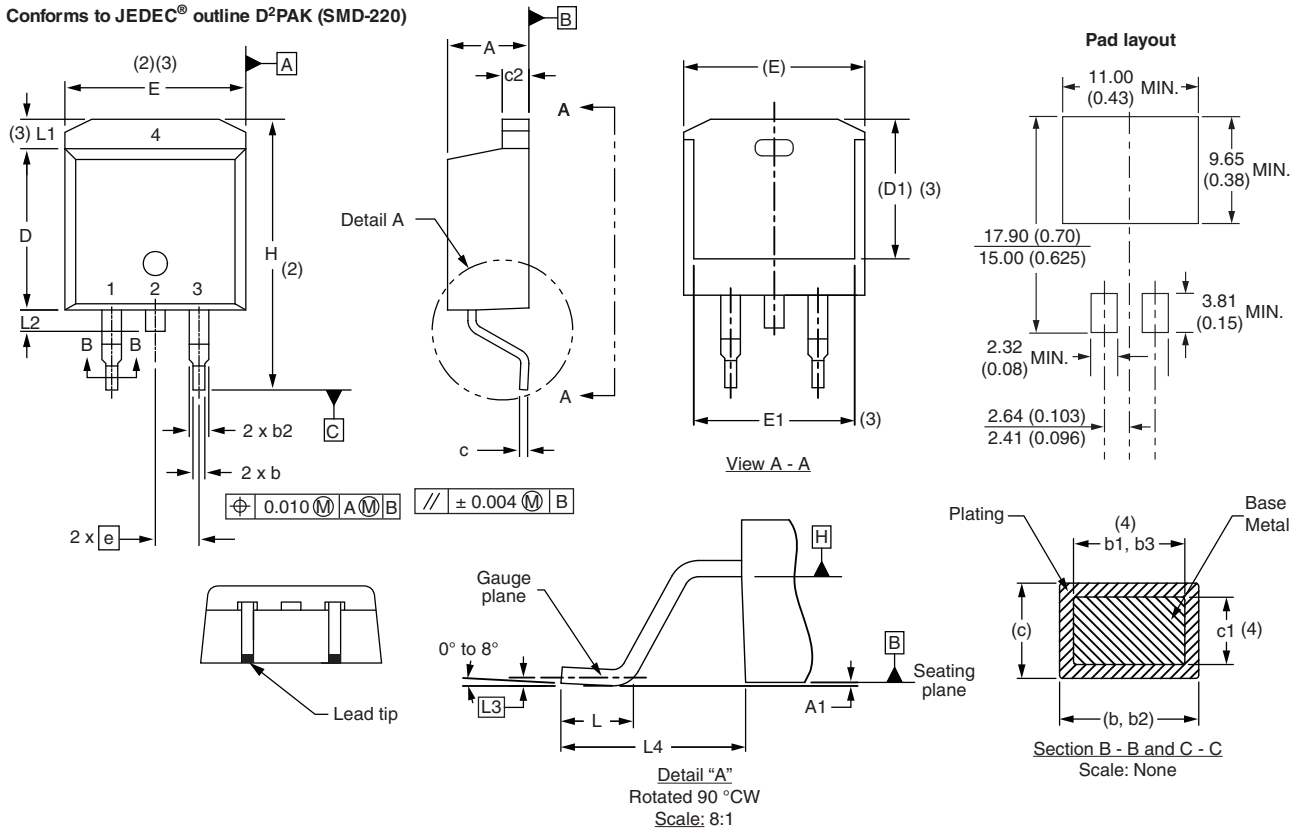
1 - Vishay Semiconductors product
2 - Essential part number
3 - B = surface mount
4 - Current rating (10 = 10 A)
5 - Voltage ratings (35 = 35 V, 45 = 45 V)
6 - • None = tube (50 pieces)
• TRL = tape and reel (left oriented)
• TRR = tape and reel (right oriented)
7 - PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95046
Part marking information	www.vishay.com/doc?95054
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?95293

D²PAK

DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D²PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
c	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
e	2.54 BSC		0.100 BSC		
H	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

(1) Dimensioning and tolerancing per ASME Y14.5 M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
(3) Thermal pad contour optional within dimension E, L1, D1 and E1
(4) Dimension b1 and c1 apply to base metal only
(5) Datum A and B to be determined at datum plane H
(6) Controlling dimension: inch
(7) Outline conforms to JEDEC® outline TO-263AB

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